NSN 5961-01-357-1125

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-357-1125 **Inclosure Material:** Metal **Overall Length:** 0.015 inches **Overall Width:** 0.015 inches **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, instantaneous **Capacitance Rating In Picofarads:** Between 0.1 and 0.37 **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 1 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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